

CPH6520

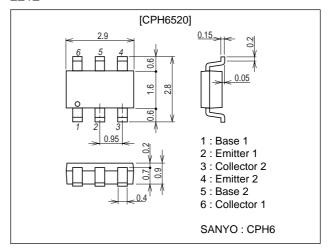
Low-Frequency General-Purpose Amplifier, Drivers Applications

Features

- Composite type with 2 transistors contained in the CPH package currently in use, improving the mounting efficiency greatly.
- The CPH6520 is formed with two chips, being equivalent to the 2SA1813, placed in one package.
- · Adoption of FBET process.
- High DC current gain (hFE=500 to 1200).
- · High VEBO (VEBO≥15V).
- Excellent in thermal equilibrium and pair capability.

Package Dimensions

unit : mm 2212



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-30	V
Collector-to-Emitter Voltage	VCEO		-25	V
Emitter-to-Base Voltage	VEBO		-15	V
Collector Current	IC		-150	mA
Collector Current (Pulse)	ICP		-300	mA
Base Current	IΒ		-30	mA
Collector Dissipation	PC	1unit	350	mW
Total Dissipation	PT		500	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	ІСВО	V _{CB} =-20V, I _E =0			-0.1	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =-10V, I _C =0			-0.1	μΑ
DC Current Gain	hFE	V _{CE} =-5V, I _C =-1mA	500	800	1200	
DC Current Gain Ratio	hFE (small/large)	V _C E=-5V, I _C =-1mA	0.7	0.98		

Marking: 3G Continued on next page.

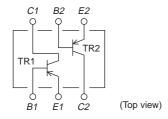
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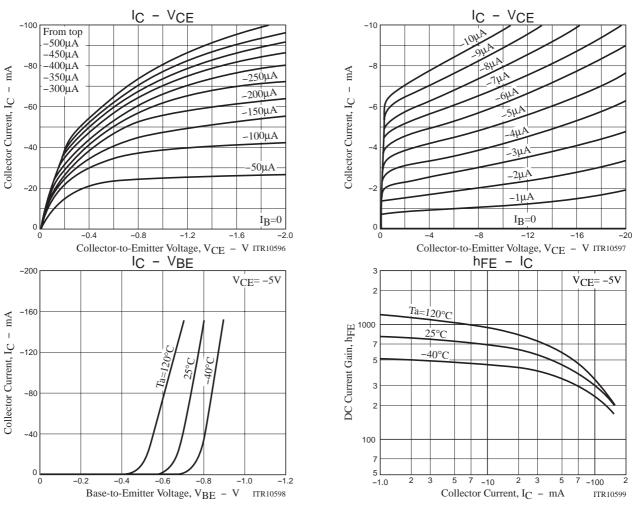
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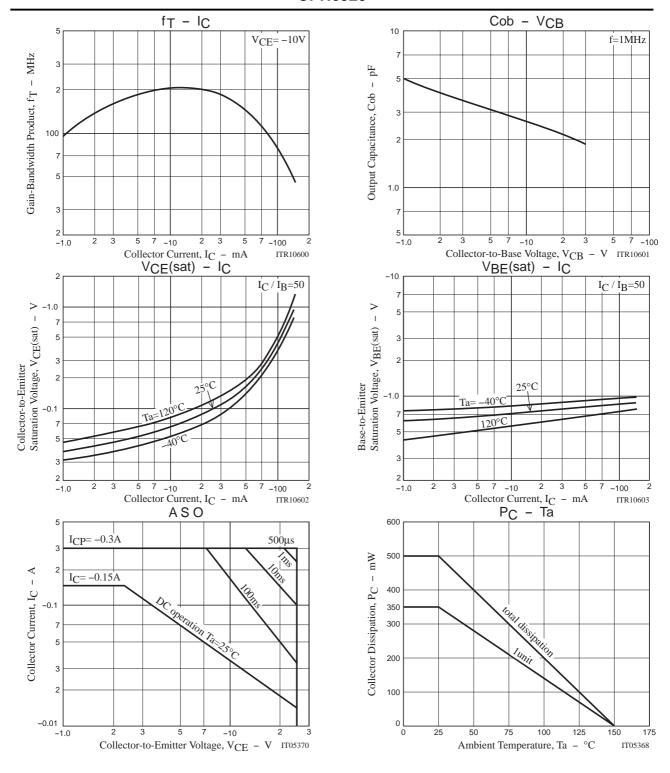
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Oill
Gain-Bandwidth Product	fT	V _{CE} =-10V, I _C =-10mA		210		MHz
Output Capacitance	Cob	V _{CB} =-10V, f=1MHz		2.6		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=-50mA, IB=-1mA		-0.15	-0.3	V
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	IC=-50mA, IB=-1mA		-0.78	-1.1	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =-10μA, I _E =0	-30			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=-1mA, RBE=∞	-25			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =-10μA, I _C =0	-15			V

Note: The specifications shown above are for each individual transistors.

Electrical Connection







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